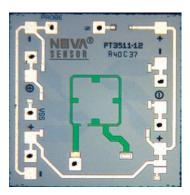


PT3512

Pressure & Temperature Sensor Die



The PT3512 piezoresistive sensor die is designed for pressure and temperature measurements using a single chip. When excited by either constant voltage or constant current, a PT3512 pressure sensor produces a differential millivolt output signal directly proportional to the applied pressure. With NovaSensor's SenStable[®] process, PT3512 die features excellent long-term stability and repeatability (< 0.1% / year typ.). The on-chip temperature sensor powered by constant current allows for high accuracy measurement of temperature and for improvement of pressure measurement accuracy.

Applications

- Process Control Systems
- Pneumatic Controls
- Hydraulic Systems
- Biomedical Controls

Features

- Highly reliable, solid state silicon pressure and temperature sensor die
- Available in Absolute and Gauge versions
- Pressure ranges: 15 to 200 PSI
- Temperature range: -40...150°C
- On-chip temperature sensor
- Die dimensions (L x W x H): 1.6 mm x 1.6 mm x 1.25 mm with glass pedestal 1.75 mm x 1.75 mm x 0.4 mm without glass pedestal
- Flexible bond pads configuration allows for wire bonding either to only one-side or along perimeter of the die.
- Media Compatibility Clean dry air, noncorrosive gases and liquids, other fluids compatible with silicon and borosilicate glass.



PT3512 Specifications

| Parameter | | Value | | | Units | Notes | | |
|--|------------------------|--|-------------------|---------------|-------------|-----------------------------|--|--|
| General | | | | | | | | |
| Pressure | | 15, 30, 50, 100, 200 | | | psig / psia | Gauge and absolute pressure | | |
| Maximum Pressure (Proof pressure) | | 6X for 15 psi, 5X for 30 psi, 4X for 50 psi, 3X for 100 and 200 psi | | | | 1 | | |
| Environmental | | | | | | | | |
| Electrostatic damage | (ESD) Class 2 | | | | | MIL-STD 883 method | | |
| Temperature Range | Operating | –40 to 150 | | | °C | –40°F to 302°F | | |
| | Storage | –55 to 160 | | | °C | –47°F to 320°F | | |
| Mechanical | | | | | | | | |
| Die Dimensions: with glass (L x W x H) | | 1.6 mm x 1.6 mm x 1.25 mm (0.84 mm thick glass) | | | | | | |
| Weight | | 0.007 grams | | | | | | |
| Metallization | | Titanium-Aluminum | | | | | | |
| Media Compatibility | | Clean dry air, noncorrosive gases and liquids, other fluids compatible with silicon and borosilicate glass | | | | | | |
| Electrical Performar | nce – Pressure Sensor | | | | | | | |
| Parameter | Range | Min | Typical | Max | Units | Notes | | |
| Recommended Current Excitation Voltage | | | 1.0 | 1.6 | mA | - | | |
| | | 5.0 | 10 | V | | - | | |
| Input and Output Impedance | | 4500 | 5500 | 6500 | Ohm | 2 | | |
| Zero Offset | | -10 | within ±2.5 | +10 | mV/V | 2, 3 | | |
| Sensitivity & Full Scal | e Output (FSO or Span) | See | e PT3511 Ordering | Information T | able | 2 | | |
| Lineority | 15 psi, 100 psi, 200 | -0.25 | within ±0.15 | +0.25 | 0/ 500 | 2, 4 | | |
| Linearity | 30 to 150 psi | -0.15 | within ±0.10 | +0.15 | %FSO | 2, 4 | | |
| Zero Pressure Repeatability | | -0.05 | within ±0.01 | +0.05 | %FSO | 2 | | |
| Thermal Coefficient of Zero (TCO) | | -15 | within ±5 | +15 | µV/V/°C | 5, 6 | | |
| Thermal Coefficient of Resistance (TCR) | | 0.31 | 0.36 | 0.41 | %/°C | 5, 6 | | |
| Thermal Coefficient of Sensitivity (TCS) | | -0.22 | -0.15 | -0.13 | %/°C | 5, 6 | | |
| Zero Thermal Hysteresis | | -0.2 | within ±0.01 | +0.2 | %FSO | 5, 6 | | |
| FSO Thermal Hystere | esis | -0.2 | within ±0.02 | +0.2 | %FSO | 5, 6 | | |
| Electrical Performar | nce – Temperature Sen | sor | | | | | | |
| Recommended excita | ation | 10 | 20 | 100 | μA | 7 | | |
| Temperature Range | | -40 | - | 150 | °C | - | | |
| Output at 25°C | | 520 | 560 | 600 | mV | 8 | | |
| Sensitivity | | -2.35 | -2.15 | -1.95 | mV/°C | 9 | | |
| FSO | | 350 | 380 | 410 | mV | 9 | | |
| Linearity | | -0.6 | within ±0.3 | 0.6 | % | 4, 9 | | |
| Linearity | | | | | | | | |

Notes:

1. Proof Pressure: The maximum pressure which the sensor may be subjected to, as an uncommon occurrence & for a short duration of time, without permanent damage & without performance degradation. Die can be used in applications requiring higher overpressure rating after additional characterization. Burst pressure is typically higher than proof pressure

2. Tested using 1.0 mA excitation at 25 °C.

3. 0 kPaA for absolute sensors, 0 kPaG for differential or gage sensors.

4. Best fit straight line.

5. Parameters are evaluated between 86°F and 176°F (30°C and 80°C) by testing samples from each wafer, typical range.

6. Between -48°F and 302°F (-40°C and 150°C) with respect to 25 °C, typical range.

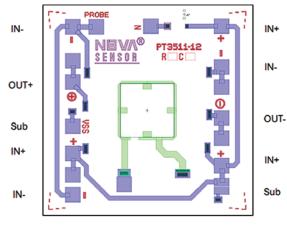
7. 20 µA constant current excitation is recommended.

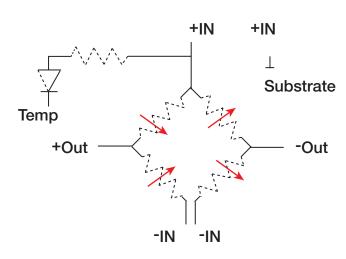
8. Tested using 20 μA excitation at 25 °C.

9. Sensitivity, FSO and Linearity of temperature sensor provided for -40...+140 °C range using 20 µA excitation.

10. Typical value.

PT3512 Wire Bond Diagram and Schematic





PT3512 Wire Bond Diagram

PT3512 Wire Bond Schematic Diagram

PT3512 Ordering Information

| PN | Range | | Gage/ | Sensitivity | FSO (mV) | | |
|-------|-------|-------------|--------------|-------------|----------|---------|-----|
| | PSI | kPa | Absolute | (mV/V/PSI) | Min | Typical | Max |
| 71792 | 15 | 103.4 | G | 1.09-1.64 | 90 | 100-110 | 135 |
| 71793 | 15 | 103.4 | А | 1.09-1.64 | 90 | 100-110 | 135 |
| 71794 | 30 | 206.8 | G | 0.61-0.91 | 100 | 120-140 | 150 |
| 71795 | 30 | 206.8 | А | 0.61-0.91 | 100 | 120-140 | 150 |
| 71796 | 50 | 344.7 | G | 0.25-0.38 | 70 | 85-95 | 105 |
| 71797 | 50 | 344.7 | А | 0.25-0.38 | 70 | 85-95 | 105 |
| 71798 | 100 | 689.4 | G | 0.18-0.27 | 100 | 110-130 | 150 |
| 71799 | 100 | 689.4 | А | 0.18-0.27 | 100 | 110-130 | 150 |
| 71800 | 150 | 1034.2 | G | 0.12-0.18 | 100 | 110-130 | 150 |
| 71801 | 150 | 1034.2 | А | 0.12-0.18 | 100 | 110-130 | 150 |
| 71802 | 15-30 | 103.4-206.8 | G | 0.85-1.27 | 70 | 80-90 | 105 |
| 71803 | 15-30 | 103.4-206.8 | А | 0.85-1.27 | 70 | 80-90 | 105 |
| 71804 | 30-50 | 206.8-344.7 | G | 0.61-0.91 | 100 | 110-130 | 150 |
| 71805 | 30-50 | 206.8-344.7 | А | 0.61-0.91 | 100 | 110-130 | 150 |
| 71807 | 30 | 206.8 | G (no glass) | 0.67-1.09 | 110 | 130-150 | 180 |
| 71822 | 100 | 689.4 | G (no glass) | 0.20-0.33 | 110 | 130-150 | 180 |

All products are supplied either on 6" wafers or in Gel-Paks. Minimum release quantity: 3700 (sawn wafer on tape), 100 (die in Gel-Paks).

For ordering: sawn wafer on tape, see part number in column A.

For gel-pak option, example part number is 71805-GP.

FSO for all products are reported at 1mA excitation.

Note: Both IN+ and Sub need to be connected to the highest potential in the circuitry.

Shipping and Handling

The standard products are available on tape with metal frame and are shipped in protective plastic containers. Electrical rejects and visual rejects are inked.

Each wafer will have the following information: Lot #, Wafer #, Part #, and the number of good (yielded) die.

Warranty

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